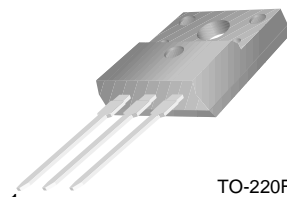


FJPF5555

High Voltage Switch Mode Application

- Fast Speed Switching
- Wide Safe Operating Area
- Suitable for Electronic Ballast Application



TO-220F
1.Base 2.Collector 3.Emitter

NPN Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------|---------------------------|------------|------------------|
| V_{CBO} | Collector-Base Voltage | 1050 | V |
| V_{CEO} | Collector-Emitter Voltage | 400 | V |
| V_{EBO} | Emitter-Base Voltage | 14 | V |
| I_C | Collector Current (DC) | 5 | A |
| I_{CP} | Collector Current (Pulse) | 10 | A |
| P_C | Collector Dissipation | 40 | W |
| T_J | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature | - 55 ~ 150 | $^\circ\text{C}$ |

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|---------------|--------------------------------------|--|------|------|------|---------------|
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C=500\mu\text{A}, I_E=0$ | 1050 | | | V |
| BV_{CEO} | Collector-Emitter Breakdown Voltage | $I_C=5\text{mA}, I_B=0$ | 400 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E=500\mu\text{A}, I_C=0$ | 14 | | | V |
| h_{FE} | * DC Current Gain | $V_{CE}=5\text{V}, I_C=10\text{mA}$ | 10 | | | |
| | | $V_{CE}=3\text{V}, I_C=0.8\text{A}$ | 20 | | 40 | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C=1\text{A}, I_B=0.2\text{A}$ | | | 0.5 | V |
| | | $I_C=3.5\text{A}, I_B=1.0\text{A}$ | | | 1.5 | V |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C=3.5\text{A}, I_B=1.0\text{A}$ | | | 1.2 | V |
| C_{ob} | Output Capacitance | $V_{CB}=10\text{V}, f=1\text{MHz}$ | | 45 | | pF |
| t_{ON} | Turn On Time | $V_{CC}=125\text{V}, I_C=0.5\text{A}$ | | | 1.0 | μs |
| t_{STG} | Storage Time | $I_{B1}=45\text{mA}, I_{B2}=0.5\text{A}$ | | | 1.2 | μs |
| t_F | Fall Time | $R_L=250\Omega$ | | | 0.3 | μs |
| t_{ON} | Turn On Time | $V_{CC}=250\text{V}, I_C=2.5\text{A}$ | | | 2.0 | μs |
| t_{STG} | Storage Time | $I_{B1}=0.5\text{A}, I_{B2}=1.0\text{A}$ | | | 2.5 | μs |
| t_F | Fall Time | $R_L=100\Omega$ | | | 0.3 | μs |

* Pulse test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

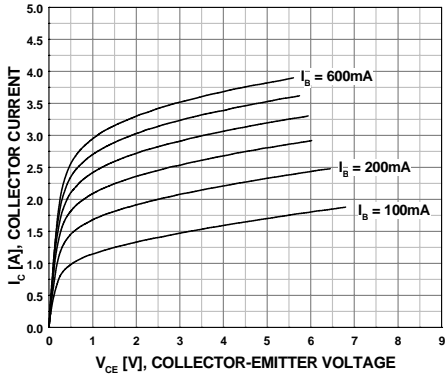


Figure 1. Static Characteristics

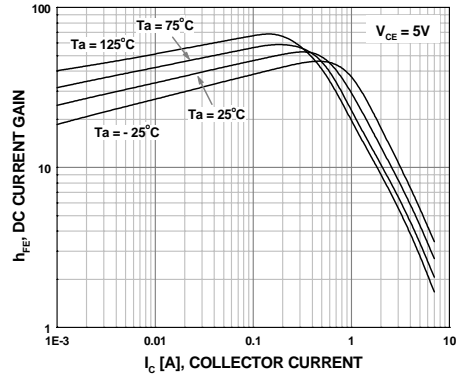


Figure 2. DC Current Gain

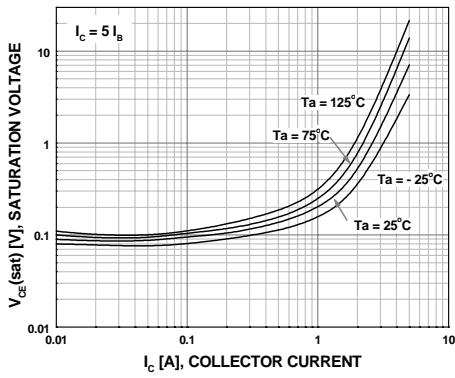


Figure 3. Saturation Voltage

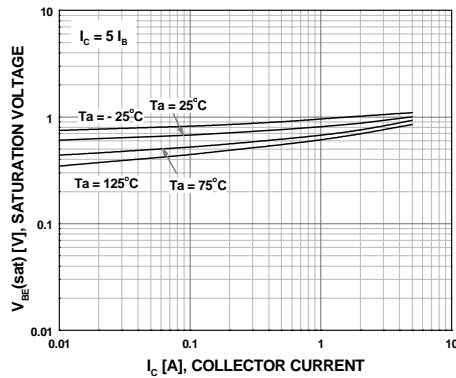


Figure 4. Saturation Voltage

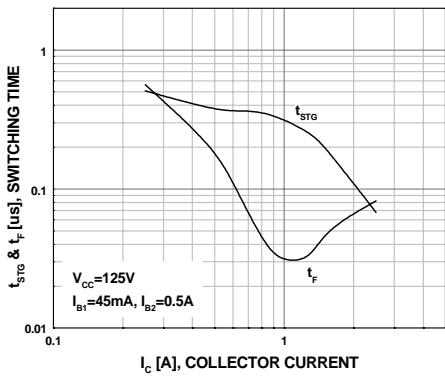


Figure 5. Resistive Load Switching

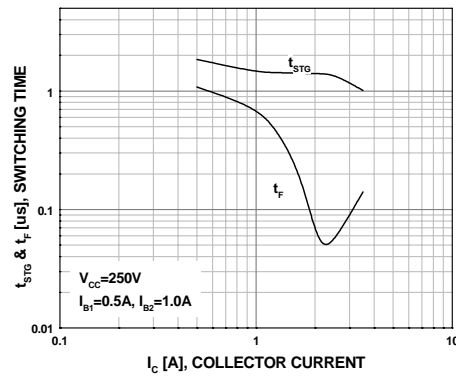


Figure 6. Resistive Load Switching

Typical Characteristics (Continued)

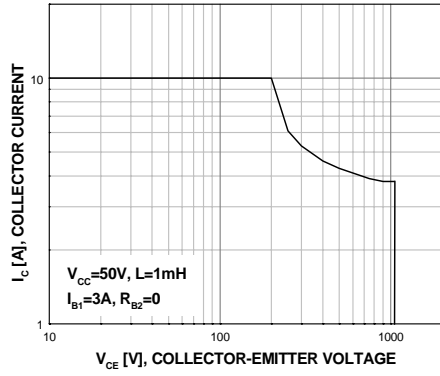


Figure 7. Reverse Biased Safe Operating Area

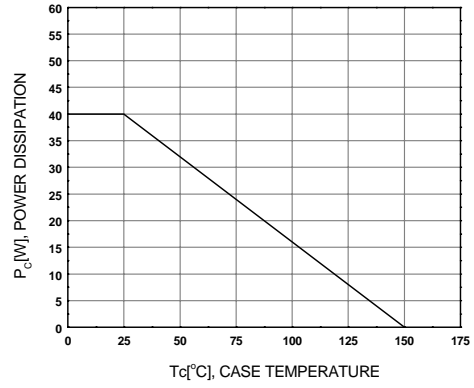


Figure 8. Power Derating

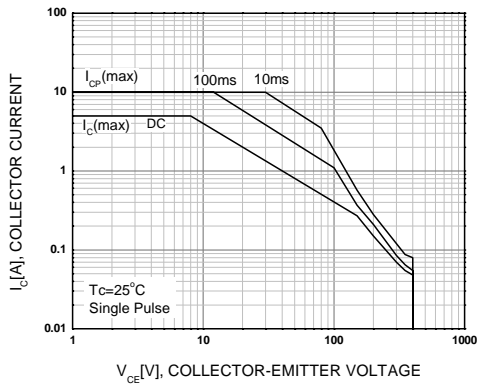
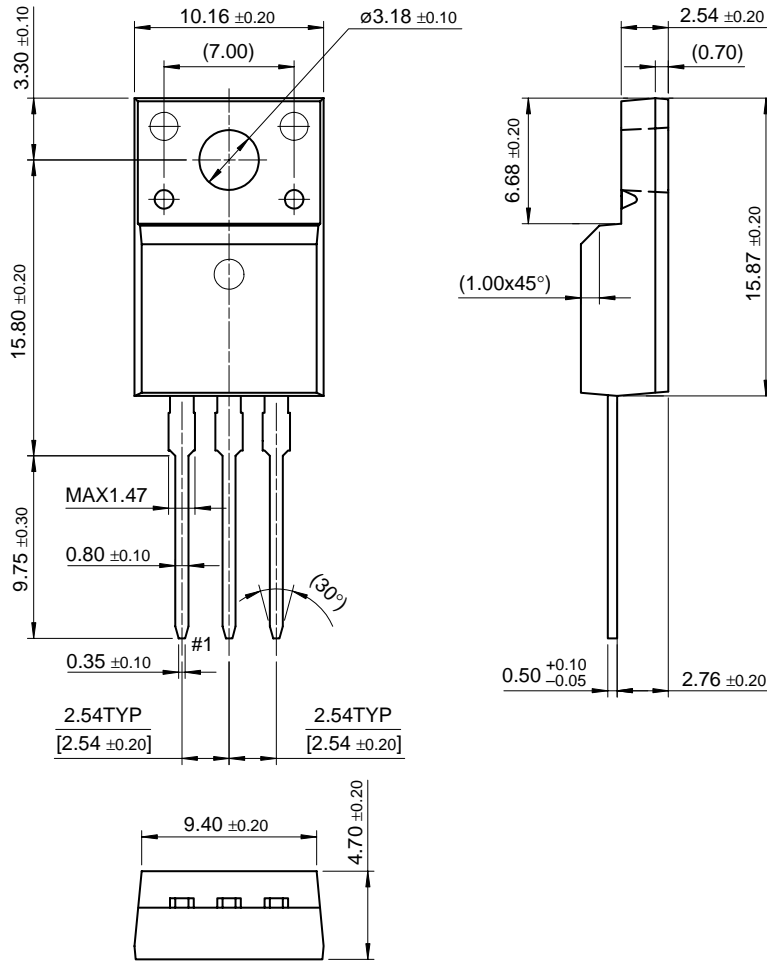


Figure 9. Forward Biased Safe Operating Area

Package Dimensions

FJPF5555

TO-220F



Dimensions in Millimeters

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